

Abstract Submitted  
for the MAR07 Meeting of  
The American Physical Society

**First principles study of the electronic structure and phonon properties for Al and C-doped MgB<sub>2</sub>** O. DE LA PEÑA-SEAMAN, R. DE COSS, Department of Applied Physics, Cinvestav-Merida, Mexico, R. HEID, K.-P. BOHNEN, Institut fuer Festkoerperphysik, Forschungszentrum Karlsruhe, Germany — We have studied the structural, electronic and lattice dynamic properties of the superconducting alloys Al and C-doped MgB<sub>2</sub> within the framework of density functional perturbation theory, using a mixed-basis pseudopotential method and the virtual crystal approximation (VCA) for modeling the alloy. For both systems the structural parameters were determined on the following ranges,  $0 \leq x \leq 1$  for Mg<sub>1-x</sub>Al<sub>x</sub>B<sub>2</sub> and  $0 \leq x \leq 0.4$  for MgB<sub>2(1-x)</sub>C<sub>2x</sub>, finding a very good agreement between the calculated structural parameters and experimental data. The complete phonon dispersion curves were calculated for selected Al and C-concentrations. The calculated phonon bands for MgB<sub>2</sub> using the LDA and GGA approximations are compared in detail with the experimental data available in the literature. The evolution of the full-dispersion curves are analyzed as a function of Al and C-concentration, specially the E<sub>2g</sub>-phonon mode frequency. In agreement with the experimental observed behavior, we find strong renormalization of the E<sub>2g</sub>-mode for both Al and C-doped MgB<sub>2</sub>. Additionally, we found a strong reduction of the E<sub>2g</sub>-band dispersion with the filling of the  $\sigma$ -band. This research was supported by CONACYT, México under Grant No. 43830-F.

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Date submitted: 25 Nov 2006

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